NSN 5961-01-213-0263

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-213-0263 **Inclosure Material:** Glass **Overall Length:** 0.205 inches **Terminal Length:** 1.100 inches **Overall Diameter:** 0.107 inches Joint Electronic Device Engineering Council/jedec/case Outline Designation: **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 20.0 regulator voltage **Voltage Tolerance In Percent:** -10.0/+10.0 **Current Rating Per Characteristic:** 12.50 milliamperes source cutoff current horsepower metric **Power Rating Per Characteristic:** 1.0 watts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:**

No

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